NCP391

Positive Overvoltage Protection Controller with Internal Low R_{ON} NMOS FET

The NCP391 is able to disconnect the systems from its output pin when wrong input operating conditions are detected. The system is positive overvoltage protected up to +28 V.

This device uses an internal NMOS and therefore, no external device is necessary, reducing the system cost and the PCB area of the application board.

The NCP391 is able to instantaneously disconnect the output from the input, due to integrated Low R_{ON} Power NMOS, if the input voltage exceeds the overvoltage threshold (OVLO) or falls below the undervoltage threshold (UVLO).

At powerup ($\overline{EN}$ pin = low level), the V_{out} turns on t_{on} time after the V_{in} exceeds the undervoltage threshold.

The NCP391 provides a negative going flag ($\overline{FLAG}$) output, which alerts the system that a fault has occurred.

In addition, the device has ESD−protected input (15 kV Air) when bypassed with a 1.0 µF or larger capacitor.

Features

- Overvoltage Protection up to 28 V
- On−Chip Low $R_{DS(on)}$ NMOS Transistor
- Internal Charge Pump
- Overvoltage Lockout (OVLO)
- Undervoltage Lockout (UVLO)
- Soft−Start
- Alert $\overline{FLAG}$ Output
- Shutdown $\overline{EN}$ Input
- Compliance to IEC61000−4−2 (Level 4)
    8.0 kV (Contact)
    15 kV (Air)
- ESD Ratings: Machine Model = B
                Human Body Model = 2
- WLCSP6 1.31x1.04 mm Package
- This is a Pb−Free Device

Applications

- Cell Phones
- Camera Phones
- Digital Still Cameras
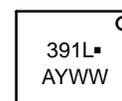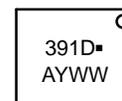- Personal Digital Applications
- MP3 Players

PIN CONNECTIONS

IN 1	EN 6
IN 2	GND 5
OUT 3	FLAG 4

or

IN A1	EN B1
IN A2	GND B2
OUT A3	FLAG B3

(Top View)   (Top View)
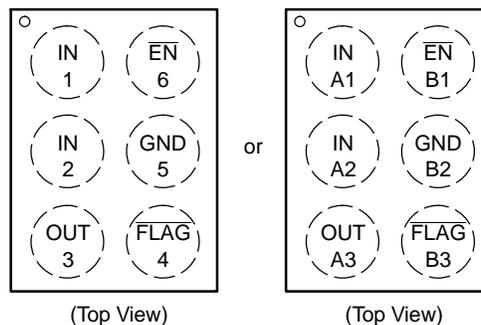
ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 12 of this data sheet.

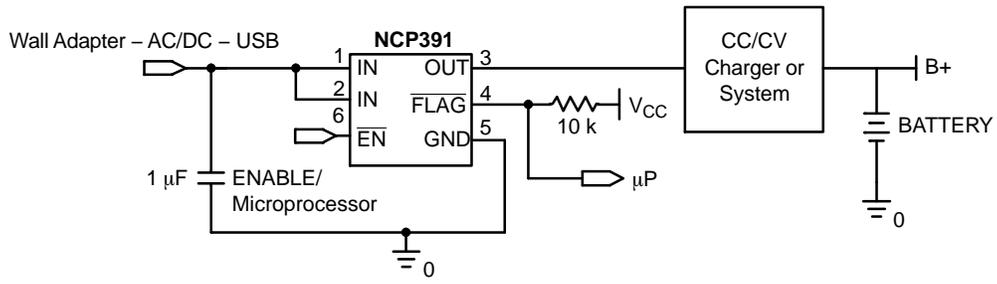Publication Order Number:
NCP391/D

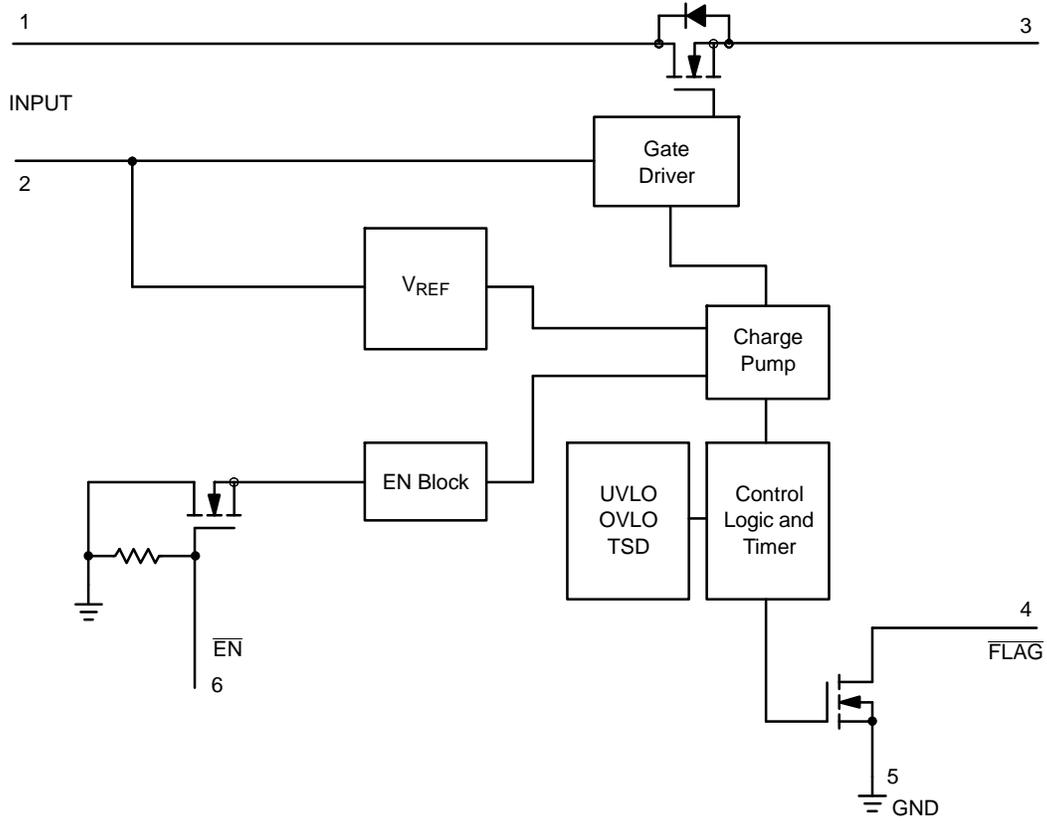# NCP391

Figure 1. Typical Application Circuit

Figure 2. Functional Block Diagram

NCP391

PIN FUNCTION DESCRIPTION

Pin No.	Symbol	Function	Description
1, 2 or A1, A2	IN	INPUT	Input Voltage Pins. These pins are connected to the Wall Adapoter (AC–DC, Vbus ..). A 1 μF low ESR ceramic capacitor, or larger, must be connected between these pins and GND, as close as possible to the DUT. The two IN pins must be connected together to power supply. (See PCB recommendation for the pin7).
3 or A3	OUT	OUTPUT	Output Voltage Pins. This pin follows IN pins when "no fault" is detected.
4 or B3	$\overline{\text{FLAG}}$	OUTPUT	Fault Indication Pin. This pin allows an external system to detect a fault on the IN pins. The $\overline{\text{FLAG}}$ pin goes low when input voltage exceeds OVLO threshold or drops below UVLO threshold or when TSD is exceeded. Since the $\overline{\text{FLAG}}$ pin is open drain functionality, an external pull–up resistor to V_{CC} must be added. (Minimum 10 kΩ).
5 or B2	GND	POWER	Ground
6 or B1	$\overline{\text{EN}}$	INPUT	Enable Pin. The device enters in shutdown mode when this pin is tied to a high level. In this case the output is disconnected from the input. To allow normal functionality, the $\overline{\text{EN}}$ pin shall be connected to GND to a pull down or to a I/O pin. This pin does not have an impact on the fault detection.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Minimum Voltage (IN to GND)	$Vmin_{in}$	−0.3	V
Minimum Voltage (All others to GND)	Vmin	−0.3	V
Maximum Voltage (IN to GND)	$Vmax_{in}$	30	V
Maximum Voltage (All others to GND)	Vmax	7.0	V
Maximum Current (UVLO<V_{IN}<OVLO)	Imax	2.0	A
Maximum Peak Current (t $\leq$ 1 ms, T_A = 85°C)	$Imax_{peak}$	4.0	A
Thermal Resistance, Junction–to–Air (Note 1)	$R_{\theta JA}$	130	°C/W
Operating Ambient Temperature Range	T_A	−40 to +85	°C
Storage Temperature Range	T_{stg}	−65 to +150	°C
Junction Operating Temperature	T_J	150	°C
ESD Withstand Voltage (IEC 61000–4–2) (input only) when bypassed with 1.0 μF capacitor 　Human Body Model (HBM), Model = 2 (Note 2) 　Machine Model (MM) Model = B (Note 3)	Vesd	15 Air, 8.0 Contact 2000 200	kV V V
Moisture Sensitivity	MSL	Level 1	–

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.
1. The $R_{\theta JA}$ is highly dependent on the PCB heat sink area (connected to pin 7).
2. Human Body Model, 100 pF discharged through a 1.5 kΩ resistor following specification JESD22/A114.
3. Machine Model, 200 pF discharged through all pins following specification JESD22/A115.

NCP391

ELECTRICAL CHARACTERISTICS – NCP391FCALT2G (Min/Max limits values (–40°C < T_A < +85°C) and V_{in} = +5.0 V. Typical values are T_A = +25°C, unless otherwise noted.)

Characteristic	Symbol	Conditions	Min	Typ	Max	Unit
Input Voltage Range	V_{in}	–	1.2	–	28	V
Undervoltage Lockout Threshold (Note 4) NCP391FCAL	UVLO	V_{in} falls below UVLO threshold from 5 V to 2.7 V	2.8	2.95	3.1	V
Undervoltage Lockout Hysteresis	$UVLO_{hyst}$	V_{in} rises above UVLO + $UVLO_{hyst}$	30	60	90	mV
Overvoltage Lockout Threshold (Note 4) NCP391FCAL	OVLO	V_{in} rises above OVLO threshold	7.16	7.4	7.65	V
Overvoltage Lockout Hysteresis NCP391FCAL	$OVLO_{hyst}$	V_{in} falls below OVLO + $OVLO_{hyst}$	50	100	150	mV
V_{in} versus V_{out} Resistance	$R_{DS(on)}$	V_{in} = 5.0 V, $\overline{EN}$ = GND, Load connected to V_{out}	–	120	200	mΩ
Supply Quiescent Current	Idd	No load. $\overline{EN}$ = 5.0 V	–	70	150	μA
		No load. $\overline{EN}$ = Gnd	–	90	170	μA
UVLO Supply Current	Idd_{uvlo}	V_{IN} = 2.7 V	–	60	–	μA
MOSFET Leakage	I_{vdss}	V_{IN} = 28 V	–	10	500	nA
$\overline{FLAG}$ Output Low Voltage	Vol_{flag}	1.2 V < V_{IN} < UVLO Sink 50 μA on $\overline{FLAG}$ pin	–	20	400	mV
		V_{IN} > OVLO Sink 1.0 mA on $\overline{FLAG}$ pin	–	–	400	mV
$\overline{FLAG}$ Leakage Current	$\overline{FLAG}_{leak}$	$\overline{FLAG}$ level = 5.0 V	–	1.0	–	nA
$\overline{EN}$ Voltage High	Vih	–	1.2	–	–	V
$\overline{EN}$ Voltage Low	Vol	–	–	–	0.4	V
$\overline{EN}$ Leakage Current	$\overline{EN}_{leak}$	$\overline{EN}$ = 5.0 V or GND	–	1.0	–	nA
Thermal Shutdown Temperature	t_{SD}	–	–	150	–	°C
Thermal Shutdown Hysteresis	t_{SDhyst}	–	–	15	–	°C

TIMINGS

Characteristic	Symbol	Conditions	Min	Typ	Max	Unit
Startup Delay	ton	From V_{in} > UVLO to V_{out} = 0.3 V (See Figures 3 & 7)	6.0	10	14	ms
$\overline{FLAG}$ Going Up Delay	tstart	From V_{out} = 0.3 V to FLAG = 1.2 V (See Figures 3 & 9)	6.0	10	14	ms
Output Turn Off Time	toff	From V_{in} > OVLO to V_{out} < = 0.3 V (See Figures 4 & 8) V_{in} increasing from 5.0 V to 8.0 V at 3.0 V/μs Rload connected on V_{out}	–	1.5	5.0	μs
Alert Delay	tstop	From V_{in} > OVLO to $\overline{FLAG}$ < = 0.4 V (See Figures 4 & 10) V_{in} increasing from 5.0 V to 8.0 V at 3.0 V/μs Rload connected on V_{out}	–	1.0	–	μs
Disable Time	tdis	From $\overline{EN}$ > = 1.2 V to V_{out} < 0.3 V Rload = 5.0 Ω (See Figures 5 & 12)	–	1.0	5.0	μs

NOTE: Electrical parameters are guaranteed by correlation across the full range of temperature.
4. Additional UVLO and OVLO thresholds ranging from UVLO and from OVLO can be manufactured. Contact your ON Semiconductor representative for availability.

ELECTRICAL CHARACTERISTICS – NCP391FCCADT2G (Min/Max limits values (−40°C < T_A < +85°C) and V_{in} = +4.2 V. Typical values are T_A = +25°C, unless otherwise noted.)

Characteristic	Symbol	Conditions	Min	Typ	Max	Unit
Input Voltage Range	V_{in}	–	1.2	–	28	V
Undervoltage Lockout Threshold (Note 5)	UVLO	V_{in} falls below UVLO threshold from 4.2 V to 2.7 V	2.8	2.95	3.1	V
Undervoltage Lockout Hysteresis	$UVLO_{hyst}$	V_{in} rises above UVLO + $UVLO_{hyst}$	30	60	90	mV
Overvoltage Lockout Threshold (Note 5)	OVLO	V_{in} rises above OVLO threshold	4.8	4.95	5.1	V
Overvoltage Lockout Hysteresis	$OVLO_{hyst}$	V_{in} falls below OVLO + $OVLO_{hyst}$	50	100	150	mV
V_{in} versus V_{out} Resistance	$R_{DS(on)}$	V_{in} = 4.2 V, $\overline{EN}$ = GND, Load connected to V_{out}	–	120	200	mΩ
Supply Quiescent Current	Idd	No load. $\overline{EN}$ = 4.2 V	–	70	150	μA
		No load. $\overline{EN}$ = Gnd	–	90	170	μA
UVLO Supply Current	Idd_{uvlo}	V_{IN} = 2.7 V	–	60	–	μA
MOSFET Leakage	I_{vdss}	V_{IN} = 28 V	–	10	500	nA
$\overline{FLAG}$ Output Low Voltage	Vol_{flag}	1.2 V < V_{IN} < UVLO Sink 50 μA on $\overline{FLAG}$ pin	–	20	400	mV
		V_{IN} > OVLO Sink 1.0 mA on $\overline{FLAG}$ pin	–	–	400	mV
$\overline{FLAG}$ Leakage Current	$\overline{FLAG}_{leak}$	$\overline{FLAG}$ level = 4.2 V	–	1.0	–	nA
$\overline{EN}$ Voltage High	Vih	–	1.2	–	4.95	V
$\overline{EN}$ Voltage Low	Vol	–	–	–	0.4	V
$\overline{EN}$ Leakage Current	$\overline{EN}_{leak}$	$\overline{EN}$ = 4.2 V or GND	–	1.0	–	nA
Thermal Shutdown Temperature	t_{SD}	–	–	150	–	°C
Thermal Shutdown Hysteresis	t_{SDhyst}	–	–	15	–	°C

TIMINGS

Characteristic	Symbol	Conditions	Min	Typ	Max	Unit
Startup Delay	ton	From V_{in} > UVLO to V_{out} = 0.3 V (See Figures 3 & 7)	6.0	10	14	ms
$\overline{FLAG}$ Going Up Delay	tstart	From V_{out} = 0.3 V to FLAG = 1.2 V (See Figures 3 & 9)	6.0	10	14	ms
Output Turn Off Time	toff	From V_{in} > OVLO to V_{out} < = 0.3 V (See Figures 4 & 8) V_{in} increasing from 4.2 V to 8.0 V at 3.0 V/μs Rload connected on V_{out}	–	1.5	5.0	μs
Alert Delay	tstop	From V_{in} > OVLO to $\overline{FLAG}$ < = 0.4 V (See Figures 4 & 10) V_{in} increasing from 4.2 V to 8.0 V at 3.0 V/μs Rload connected on V_{out}	–	1.0	–	μs
Disable Time	tdis	From $\overline{EN}$ > = 1.2 V to V_{out} < 0.3 V Rload = 5.0 Ω (See Figures 5 & 12)	–	1.0	5.0	μs

NOTE: Electrical parameters are guaranteed by correlation across the full range of temperature.

5. Additional UVLO and OVLO thresholds ranging from UVLO and from OVLO can be manufactured. Contact your ON Semiconductor representative for availability.
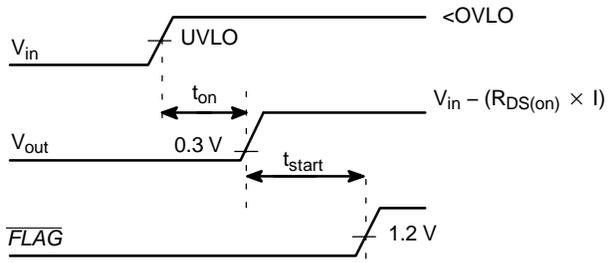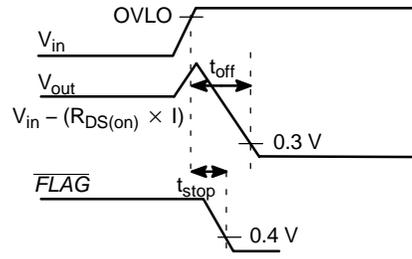
NCP391

TIMING DIAGRAMS

Figure 3. Startup

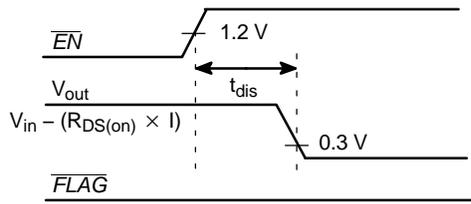**Figure 4. Shutdown on Overvoltage Detection**

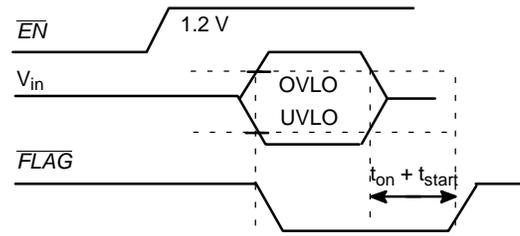

Figure 5. Disable on $\overline{EN}$ = 1

Figure 6. $\overline{FLAG}$ Response with $\overline{EN}$ = 1

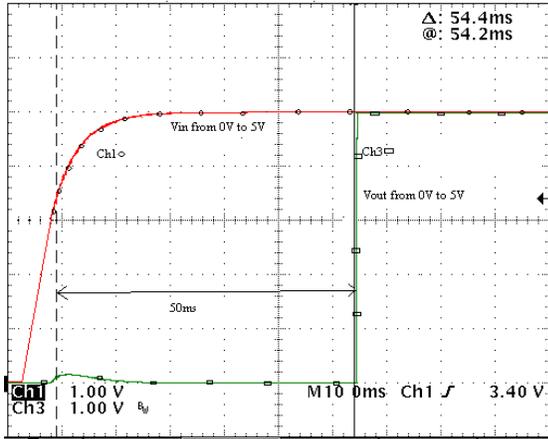## TYPICAL OPERATING CHARACTERISTICS

50 ms t_{on} and t_{start} version
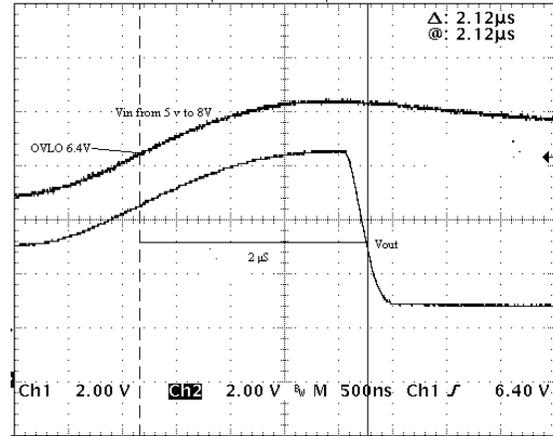

Figure 7. Startup
V_{in} = Ch1, V_{out} = Ch3

Figure 8. Output Turn Off Time
V_{in} = Ch1, V_{out} = Ch2
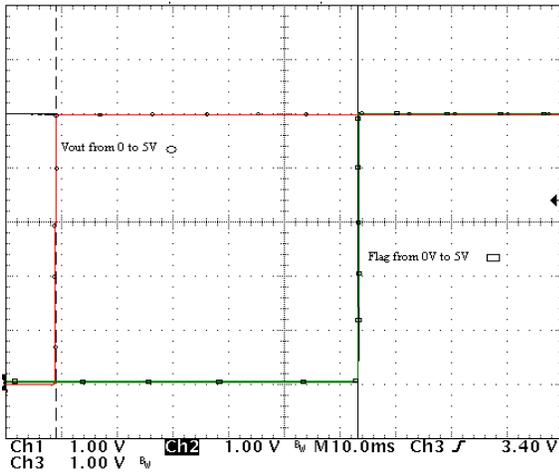
Figure 9. FLAG Going Up Delay
V_{out} = Ch3, FLAG = Ch2
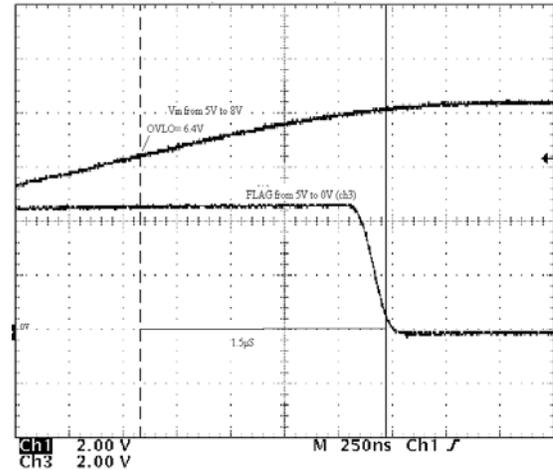
Figure 10. Alert Delay
V_{out} = Ch1, FLAG = Ch3
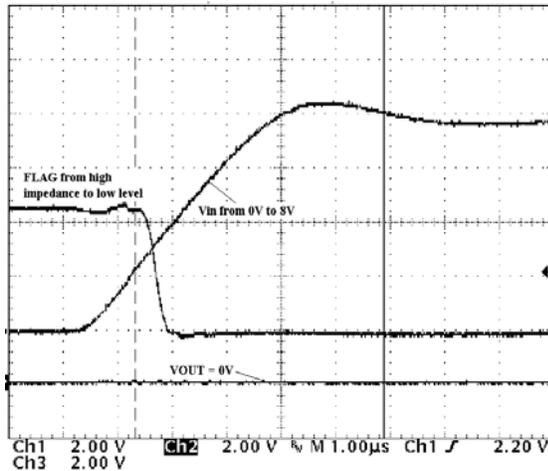
Figure 11. Initial Overvoltage Delay
V_{in} = Ch1, V_{out} = Ch2, FLAG = Ch3
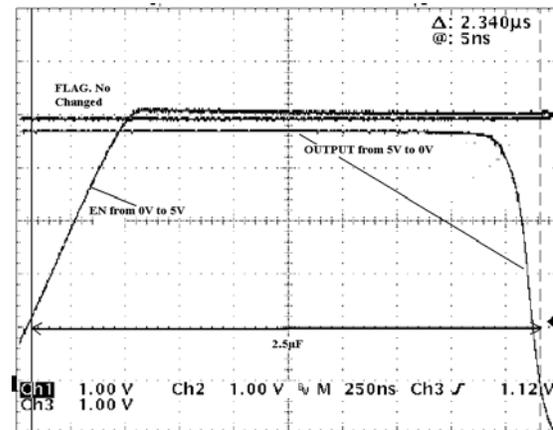
Figure 12. Disable Time
EN = Ch1, V_{out} = Ch2, FLAG = Ch3

TYPICAL OPERATING CHARACTERISTICS
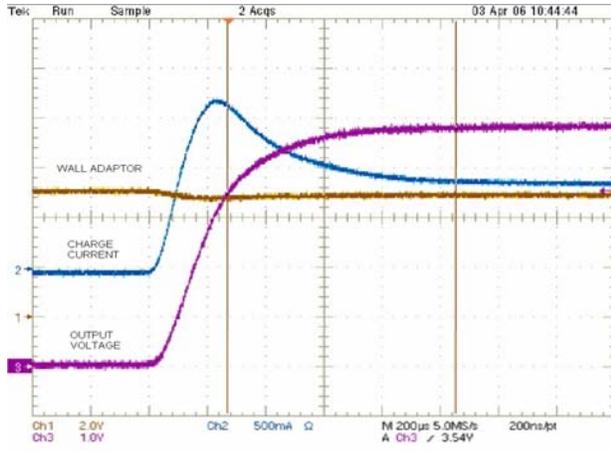
Figure 13. Inrush Current with C$_{out}$ = 100 μF, I charge = 1 A, Output Wall Adaptor Inductance 1 μH
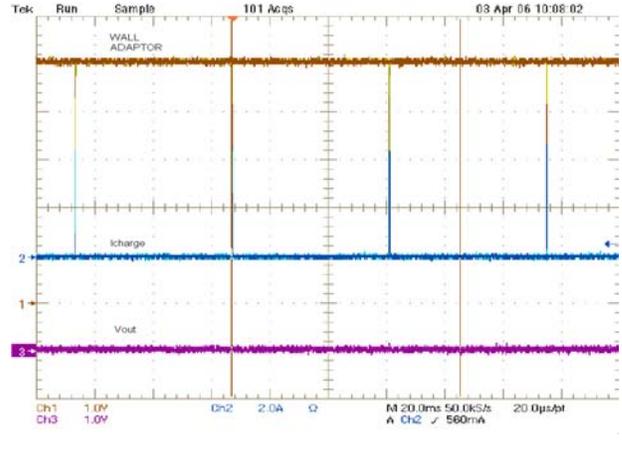
Figure 14. Output Short Circuit
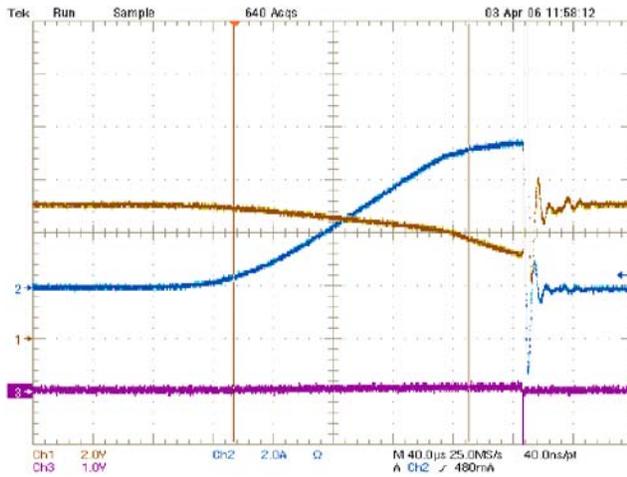
Figure 15. Output Short Circuit (Zoom Fig. 14)
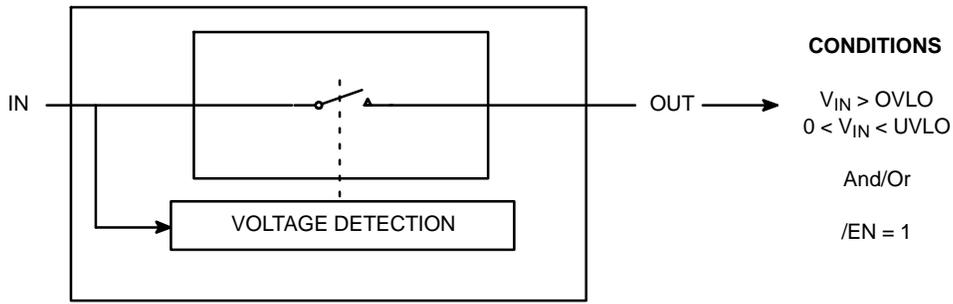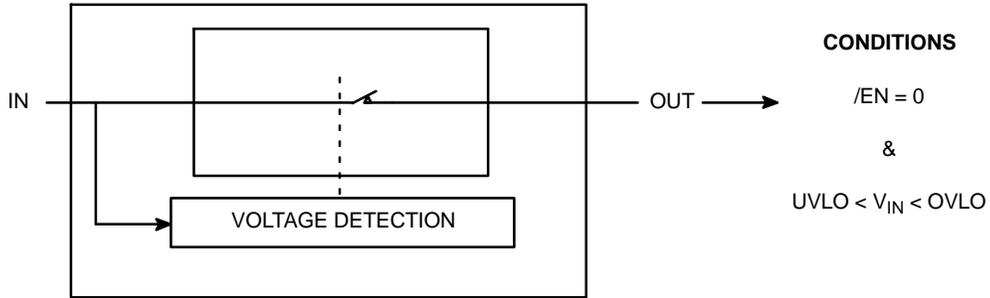
Figure 16. Simplified Diagram

Figure 17. Simplified Diagram

Operation

The NCP391 provides overvoltage protection for positive voltage, up to 28 V. A low $R_{DS(on)}$ NMOSFET protects the systems (i.e.: charger) connected on the Vout pin, against positive overvoltage. At powerup, with $\overline{EN}$ pin = low, the output is rising up t_{on} soft−start after the input overtaking undervoltage UVLO (Figure 3). The NCP391 provides a $\overline{FLAG}$ output, which alerts the system that a fault has occurred. A t_{start} additional delay, regarding available output (Figure 3) is added between output signal rising up and to $\overline{FLAG}$ signal rising up. $\overline{FLAG}$ pin is an open drain output.
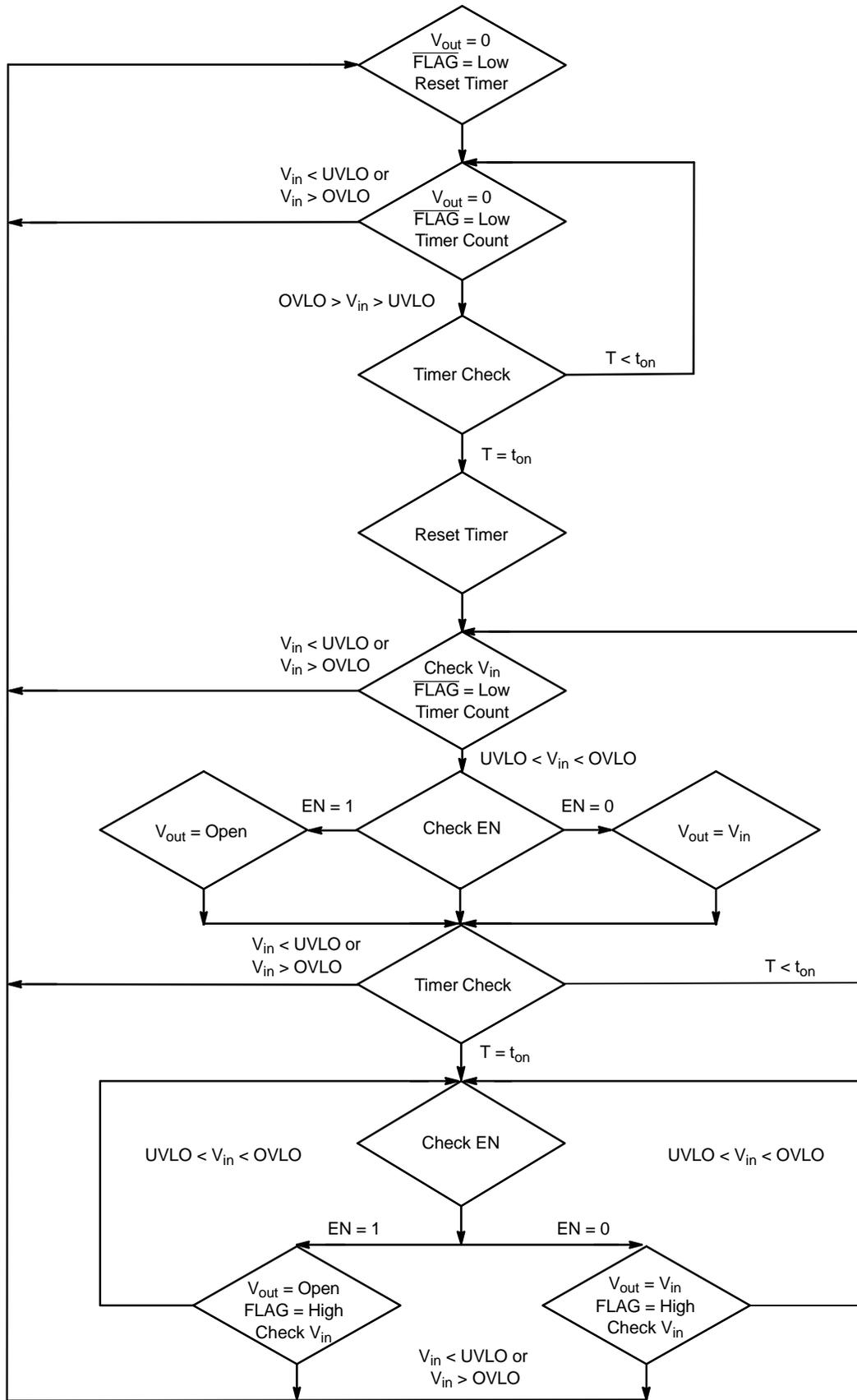
Figure 18. State Machine

Undervoltage Lockout (UVLO)

To ensure proper operation under any conditions, the device has a built–in undervoltage lockout (UVLO) circuit. During V_{in} positive going slope, the output remains disconnected from input until V_{in} voltage is below UVLO, plus hysteresis, nominal. The $\overline{FLAG}$ output is tied to low as long as V_{in} does not reach UVLO threshold. This circuit has a built–in hysteresis to provide noise immunity to transient condition. Additional UVLO thresholds ranging from UVLO can be manufactured. Contact your ON Semiconductor representative for availability.

Overvoltage Lockout (OVLO)

To protect connected systems on V_{out} pin from overvoltage, the device has a built–in overvoltage lockout (OVLO) circuit. During overvoltage condition, the output remains disabled as long as the input voltage exceeds typical OVLO. Additional OVLO thresholds ranging from OVLO can be manufactured. Contact your ON Semiconductor representative for availability.

$\overline{FLAG}$ output is tied to low until V_{in} is higher than OVLO. This circuit has a built–in hysteresis to provide noise immunity to transient conditions.

$\overline{FLAG}$ Output

The NCP391 provides a $\overline{FLAG}$ output, which alerts external systems that a fault has occurred.

This pin is tied to low as soon the OVLO threshold is exceeded or when the V_{in} level is below the UVLO threshold. When V_{in} level recovers normal condition, $\overline{FLAG}$ is held high, keeping in mind that an additional t_{start} delay has been added between available output and $\overline{FLAG}$ = high. The pin is an open drain output, thus a pull up resistor (typically 1 MΩ, minimum 10 kΩ) must be added to V_{bat}. Minimum V_{bat} supply must be 2.5 V. The $\overline{FLAG}$ level will always reflects V_{in} status, even if the device is turned off ($\overline{EN}$ = 1).

$\overline{EN}$ Input

To enable normal operation, the $\overline{EN}$ pin shall be forced to low or connected to ground. A high level on the pin, disconnects OUT pin from IN pin. $\overline{EN}$ does not overdrive an OVLO or UVLO fault.

Internal NMOSFET

The NCP391 includes an internal Low $R_{DS(on)}$ NMOS FET to protect the systems, connected on OUT pin, from positive overvoltage. Regarding electrical characteristics, the $R_{DS(on)}$, during normal operation, will create low losses on V_{out} pin.

As example: R_{load} = 8.0 Ω, V_{in} = 5.0 V
Typical $R_{DS(on)}$ = 120 mΩ, I_{out} = 615 mA
V_{out} = 8 x 0.615 = 4.926 V

NMOS losses = $R_{DS(on)}$ x $Iout^2$ = 0.12 x 0.615^2 = 45 mW

ESD Tests

The NCP391 input pin fully supports the IEC61000–4–2. 1.0 μF (minimum) must be connected between V_{in} and GND, close to the device.

That means, in Air condition, V_{in} has a ± 15 kV ESD protected input. In Contact condition, V_{in} has ± 8.0 kV ESD protected input.

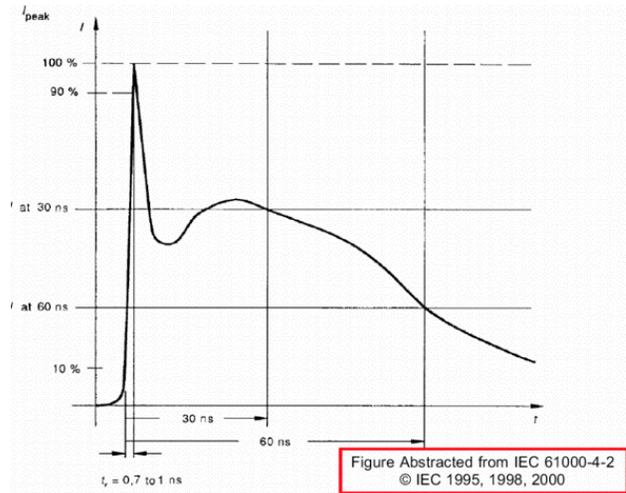Please refer to Figure 19 to see the IEC 61000–4–2 electrostatic discharge waveform.

Figure 19. Electrostatic Discharge Waveform

PCB Recommendations

The NCP391 integrates a 2 A rated NMOSFET, and the PCB rules must be respected to properly evacuate the heat out of the silicon.
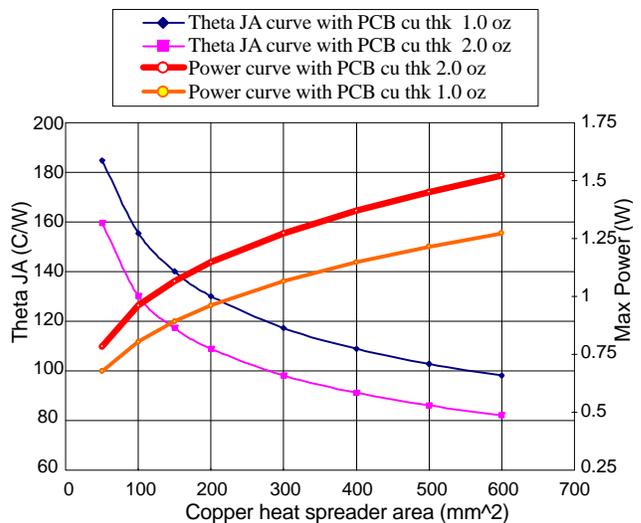

Figure 20.

NCP391

ORDERING INFORMATION

Device	Marking	Package	Shipping†
NCP391FCALT2G	391L	WLCSP6 (Pb–Free)	3000 / Tape & Reel
NCP391FCCADT2G	391D	WLCSP6 (Pb–Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

SELECTION GUIDE

The NCP391 can be available in several undervoltage and overvoltage thresholds versions. Part number is designated as follows:

NCP391FCxxT1G

a b

Code	Contents
a	UVLO Typical Threshold a: A = 2.95 V
b	OVLO Typical Threshold b: D = 4.95 V b: L = 7.4 V

NCP391

PACKAGE DIMENSIONS

WLCSP6, 1.31x1.04
CASE 499BP
ISSUE A
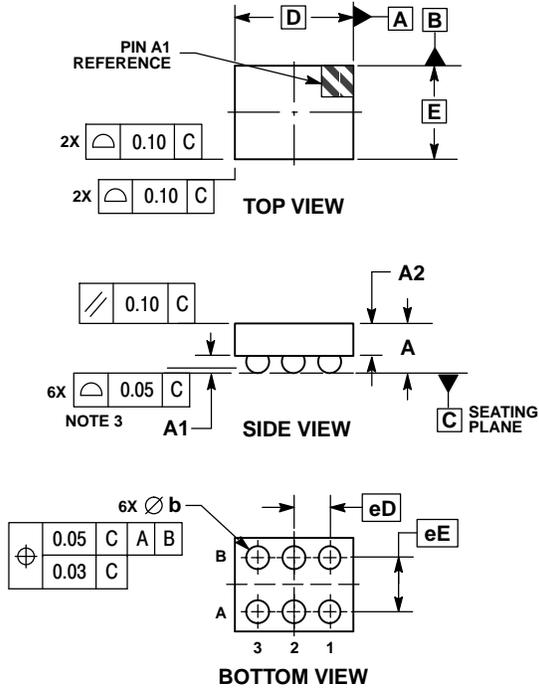
TOP VIEW

PIN A1 REFERENCE

2X ⌒ 0.10 C

2X ⌒ 0.10 C

SIDE VIEW

// 0.10 C

6X ⌒ 0.05 C

NOTE 3

A1

A2

A

C SEATING PLANE

BOTTOM VIEW

6X ∅ b

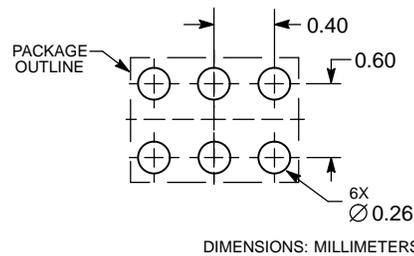⊕ 0.05 C A B

0.03 C

eD

eE

B

A

3 2 1

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

| DIM | MILLIMETERS | |
	MIN	MAX
A	0.50	0.56
A1	0.17	0.23
A2	0.33	0.39
b	0.24	0.29
D	1.31 BSC	
E	1.04 BSC	
eD	0.40 BSC	
eE	0.60 BSC	

RECOMMENDED SOLDERING FOOTPRINT*

PACKAGE OUTLINE

0.40

0.60

6X ∅ 0.26
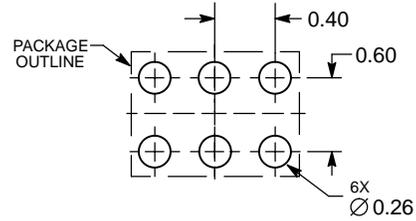
DIMENSIONS: MILLIMETERS

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NCP391

PACKAGE DIMENSIONS

WLCSP6, 1.31x1.04
CASE 567JW
ISSUE O
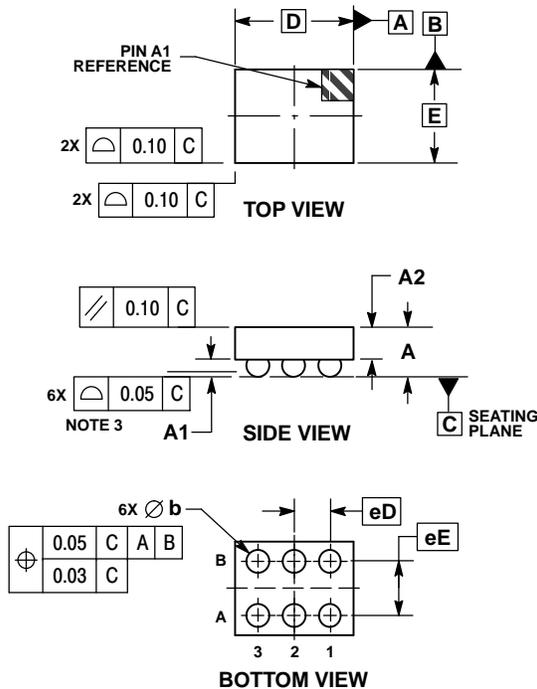
TOP VIEW

2X [⌓ | 0.10 | C]

2X [⌓ | 0.10 | C]

PIN A1 REFERENCE

SIDE VIEW

[⫽ | 0.10 | C]

6X [⌓ | 0.05 | C]

NOTE 3

A1

A2

A

C SEATING PLANE

BOTTOM VIEW

6X ⌀ b

[⊕ | 0.05 | C | A | B]
[| 0.03 | C]

3 2 1

eD

eE

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

DIM	MILLIMETERS	
	MIN	MAX
A	0.50	0.62
A1	0.17	0.23
A2	0.33	0.39
b	0.24	0.29
D	1.31 BSC	
E	1.04 BSC	
eD	0.40 BSC	
eE	0.60 BSC	

RECOMMENDED SOLDERING FOOTPRINT*

PACKAGE OUTLINE

0.40

0.60

6X ⌀ 0.26

DIMENSIONS: MILLIMETERS

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:
- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits,General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:
- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.

Как с нами связаться

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